



MT29E512G08CEHBBJ4-3ES:B TR

|                     |                                                                                                              |
|---------------------|--------------------------------------------------------------------------------------------------------------|
| Part Number:        | MT29E512G08CEHBBJ4-3ES:B TR                                                                                  |
| Manufacturer/Brand: | Micron Technology                                                                                            |
| Product description | IC FLASH 512G PARALLEL 333MHZ                                                                                |
| Datasheets:         |                                                                                                              |
| RoHs Status         |  Lead free / RoHS Compliant |
| Stock Condition     | 3326 pcs stock                                                                                               |
| Ship From           | Hong Kong                                                                                                    |
| Shipment Way        | DHL/Fedex/TNT/UPS/EMS                                                                                        |

REQUEST FOR QUOTATION

Specifications of MT29E512G08CEHBBJ4-3ES:B TR

|                                  |                                                              |
|----------------------------------|--------------------------------------------------------------|
| PART NUMBER                      | MT29E512G08CEHBBJ4-3ES:B TR                                  |
| MANUFACTURER                     | Micron Technology                                            |
| DESCRIPTION                      | IC FLASH 512G PARALLEL 333MHZ                                |
| LEAD FREE STATUS / ROHS STATUS   | Lead free / RoHS Compliant                                   |
| QUANTITY AVAILABLE               | 3326 pcs                                                     |
| DATA SHEET                       |                                                              |
| WRITE CYCLE TIME - WORD, PAGE    | -                                                            |
| VOLTAGE - SUPPLY                 | 2.5 V ~ 3.6 V                                                |
| TECHNOLOGY                       | FLASH - NAND                                                 |
| SERIES                           | -                                                            |
| PACKAGING                        | Tape & Reel (TR)                                             |
| OTHER NAMES                      | MT29E512G08CEHBBJ4-3ES:B TR-ND<br>MT29E512G08CEHBBJ4-3ES:BTR |
| OPERATING TEMPERATURE            | 0°C ~ 70°C (TA)                                              |
| MOISTURE SENSITIVITY LEVEL (MSL) | 3 (168 Hours)                                                |
| MEMORY TYPE                      | Non-Volatile                                                 |
| MEMORY SIZE                      | 512Gb (64G x 8)                                              |
| MEMORY INTERFACE                 | Parallel                                                     |
| MEMORY FORMAT                    | FLASH                                                        |
| LEAD FREE STATUS / ROHS STATUS   | Lead free / RoHS Compliant                                   |
| DETAILED DESCRIPTION             | FLASH - NAND Memory IC 512Gb (64G x 8) Parallel 333MHz       |
| CLOCK FREQUENCY                  | 333MHz                                                       |

Related Tags

|                                               |                                                    |                                                   |
|-----------------------------------------------|----------------------------------------------------|---------------------------------------------------|
| Micron Technology MT29E512G08CEHBBJ4-3ES:B TR | MT29E512G08CEHBBJ4-3ES:B TR Distributor            | MT29E512G08CEHBBJ4-3ES:B TR Supplier              |
| MT29E512G08CEHBBJ4-3ES:B TR Price             | MT29E512G08CEHBBJ4-3ES:B TR Pictures               | MT29E512G08CEHBBJ4-3ES:B TR Image                 |
| MT29E512G08CEHBBJ4-3ES:B TR PDF Datasheet     | MT29E512G08CEHBBJ4-3ES:B TR Download Datasheet     | MT29E512G08CEHBBJ4-3ES:B TR Datasheet             |
| MT29E512G08CEHBBJ4-3ES:B TR Stock             | Buy MT29E512G08CEHBBJ4-3ES:B TR                    | Buy Micron Technology MT29E512G08CEHBBJ4-3ES:B TR |
| Micron Technology MT29E512G08CEHBBJ4-3ES:B TR | Micron Technology Supplier                         | Micron Technology Distributor                     |
| Micron Technology MT29E512G08CEHBBJ4-3ES:B TR | Micron Technology Inc. MT29E512G08CEHBBJ4-3ES:B TR |                                                   |

Related Products

|                                                                                                                                                                                                                                                                     |                                                                                                                                                                                                                                                                      |
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| <div></div> <div><b>MT29E512G08CMCCBH7-6:C</b><br/>Manufacturers: Micron Technology<br/>Description: IC FLASH 512G PARALLEL 167MHZ<br/>In stock: 1334 pcs</div> <div>RFQ</div>    | <div></div> <div><b>MT29E4T08CTHBBM5-3ES:B TR</b><br/>Manufacturers: Micron Technology<br/>Description: IC FLASH 4T PARALLEL 333MHZ<br/>In stock: 403 pcs</div> <div>RFQ</div>    |
| <div></div> <div><b>MT29E4T08EYHBBG9-3:B</b><br/>Manufacturers: Micron Technology<br/>Description: IC FLASH 4T PARALLEL 333MHZ<br/>In stock: 412 pcs</div> <div>RFQ</div>         | <div></div> <div><b>MT29E512G08CKCBBH7-6:B TR</b><br/>Manufacturers: Micron Technology<br/>Description: IC FLASH 512G PARALLEL 167MHZ<br/>In stock: 2479 pcs</div> <div>RFQ</div> |
| <div></div> <div><b>MT29E512G08CMCBBH7-6:B TR</b><br/>Manufacturers: Micron Technology<br/>Description: IC FLASH 512G PARALLEL 167MHZ<br/>In stock: 2279 pcs</div> <div>RFQ</div> | <div></div> <div><b>MT29E4T08EYHBBG9-3ES:B</b><br/>Manufacturers: Micron Technology<br/>Description: IC FLASH 4T PARALLEL 333MHZ<br/>In stock: 408 pcs</div> <div>RFQ</div>       |
| <div></div> <div><b>MT29E512G08CKCCBH7-6:C</b><br/>Manufacturers: Micron Technology<br/>Description: IC FLASH 512G PARALLEL 167MHZ<br/>In stock: 1185 pcs</div> <div>RFQ</div>    | <div></div> <div><b>MT29E4T08CTHBBM5-3:B TR</b><br/>Manufacturers: Micron Technology<br/>Description: IC FLASH 4T PARALLEL 333MHZ<br/>In stock: 191 pcs</div> <div>RFQ</div>      |
| <div></div> <div><b>MT29E512G08CEHBBJ4-3:B</b><br/>Manufacturers: Micron Technology<br/>Description: IC FLASH 512G PARALLEL 333MHZ<br/>In stock: 1724 pcs</div> <div>RFQ</div>    | <div></div> <div><b>MT29E512G08CEHBBJ4-3:B TR</b><br/>Manufacturers: Micron Technology<br/>Description: IC FLASH 512G PARALLEL 333MHZ<br/>In stock: 1516 pcs</div> <div>RFQ</div> |
| <div></div> <div><b>MT29E512G08CKCCBH7-6:C TR</b><br/>Manufacturers: Micron Technology<br/>Description: IC FLASH 512G PARALLEL 167MHZ<br/>In stock: 1187 pcs</div> <div>RFQ</div> | <div></div> <div><b>MT29E512G08CMCCBH7-6:C TR</b><br/>Manufacturers: Micron Technology<br/>Description: IC FLASH 512G PARALLEL 167MHZ<br/>In stock: 1192 pcs</div> <div>RFQ</div> |